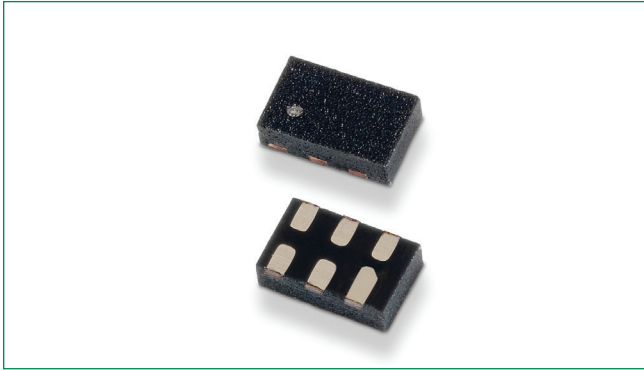
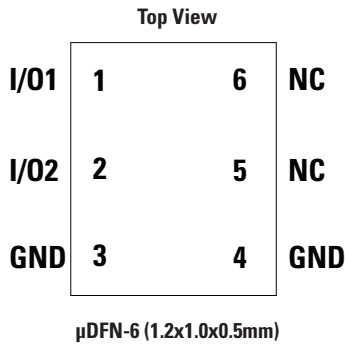


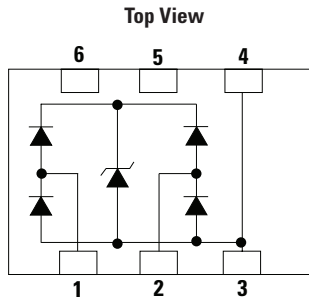
**SP3423, 0.2pF, +/-10kV Diode Array**



**Pinout**



**Functional Block Diagram**



**Applications**

- LCD/PDP TVs
- External Storages
- DVD/Blu-ray Players
- Set Top Boxes
- Smartphones
- Ultrabooks/Notebooks
- Digital Cameras
- Portable Medical
- Automotive Electronics
- Wearable Technology
- USB 2.0/3.0
- Ethernet up to 10GbE

**Description**

The SP3423 integrates 2 channels of low capacitance steering diodes and an avalanche breakdown diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). The SP3423 can safely absorb repetitive ESD strikes above the maximum contact level specified in IEC 61000-4-2 international standard ( $\pm 8\text{kV}$  contact discharge) without performance degradation.

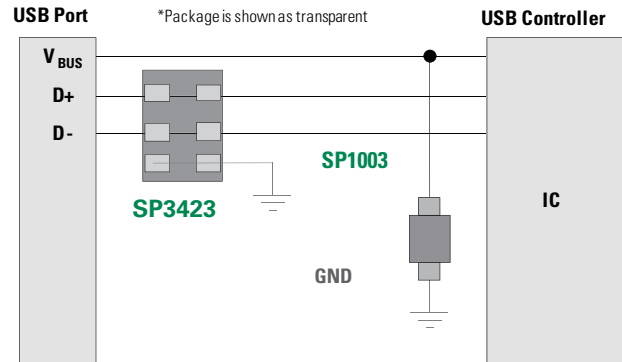
The low off-state capacitance makes it ideal for protecting high-speed signal lines such as USB2.0/3.0 and 10GbE interfaces with an extremely low dynamic resistance to protect the most sensitive, state of the art chipsets against ESD transients.

Its flow-through capability makes this SP3423 TVS a PCB layout friendly component and helps reduce stray PCB capacitances.

**Features**

- ESD, IEC 61000-4-2,  $\pm 10\text{kV}$  contact,  $\pm 15\text{kV}$  air
- EFT, IEC 61000-4-4, 80A ( $t_p=5/50\text{ns}$ )
- Lightning, 2A (8/20 $\mu\text{s}$  as defined in IEC 61000-4-5 2<sup>nd</sup> edition)
- Low capacitance of 0.2pF (TYP) per I/O
- Low leakage current of 0.01 $\mu\text{A}$  (TYP) at 5V
- Small  $\mu\text{DFN-6}$  footprint (1.2 mm x 1.0 mm x 0.5 mm)
- AEC-Q101 qualified
- Moisture Sensitivity Level(MSL -1)
- Halogen free, lead free and RoHS compliant

**USB 2.0/3.0 Protection Application Example**



Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

**Absolute Maximum Ratings**

Symbol	Parameter	Value	Units
$I_{PP}$	Peak Current ( $t_p=8/20\mu s$ )	2	A
$T_{OP}$	Operating Temperature	-40 to 125	°C
$T_{STOR}$	Storage Temperature	-55 to 150	°C

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

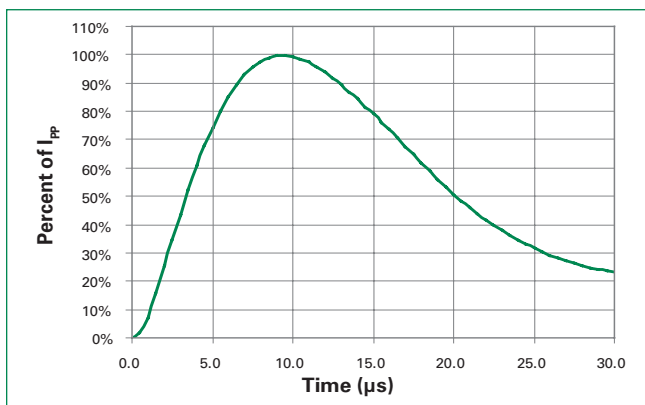
**Electrical Characteristics ( $T_{OP}=25^\circ C$ )**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	$V_{RWM}$	$I_R = 1\mu A$			5.0	V
Breakdown Voltage	$V_{BR}$	$I_R = 1mA$	7	8.4		V
Reverse Leakage Current	$I_{LEAK}$	$V_R=5V$ , Any I/O to GND		0.01	0.5	$\mu A$
Clamp Voltage <sup>1</sup>	$V_C$	$I_{PP}=1A$ , $t_p=8/20\mu s$ , Fwd		10.4	13	V
		$I_{PP}=2A$ , $t_p=8/20\mu s$ , Fwd		12.3	15	V
Dynamic Resistance <sup>2</sup>	$R_{DYN}$	TLP, $t_p=100ns$ , I/O to GND		0.65		$\Omega$
ESD Withstand Voltage <sup>1</sup>	$V_{ESD}$	IEC 61000-4-2 (Contact)	$\pm 10$			kV
		IEC 61000-4-2 (Air)	$\pm 15$			kV
Diode Capacitance	$C_{I/O-GND}$	Reverse Bias=0V, f=3 GHz		0.2		$\mu F$
	$C_{I/O-I/O}$			0.1		

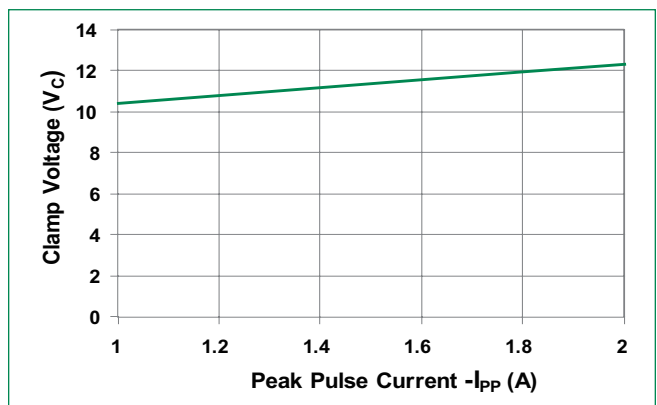
**Note:**

- Parameter is guaranteed by design and/or component characterization.
- Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window  $t1=70ns$  to  $t2=90ns$

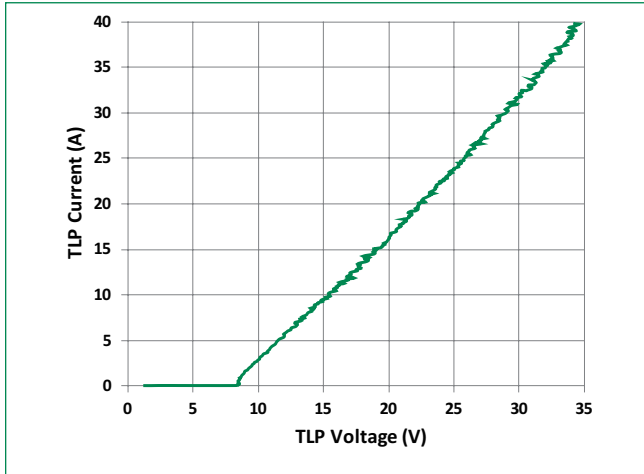
**8/20 $\mu s$  Pulse Waveform**



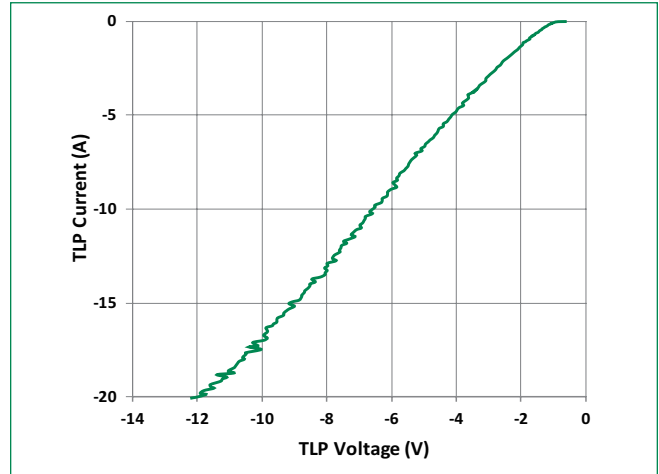
**Clamping voltage vs.  $I_{PP}$  for 8/20 $\mu s$  waveshape**



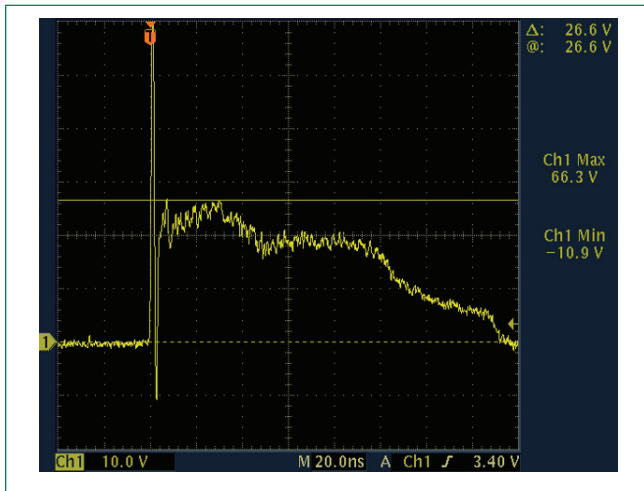
**Positive Transmission Line Pulsing (TLP) Plot**



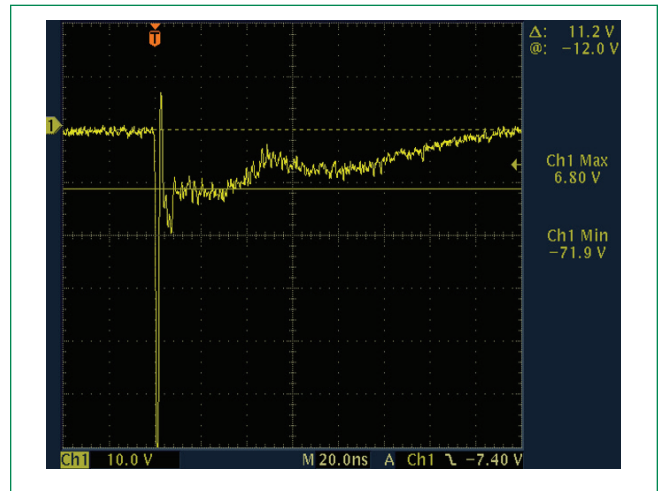
**Negative Transmission Line Pulsing (TLP) Plot**



**IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage**

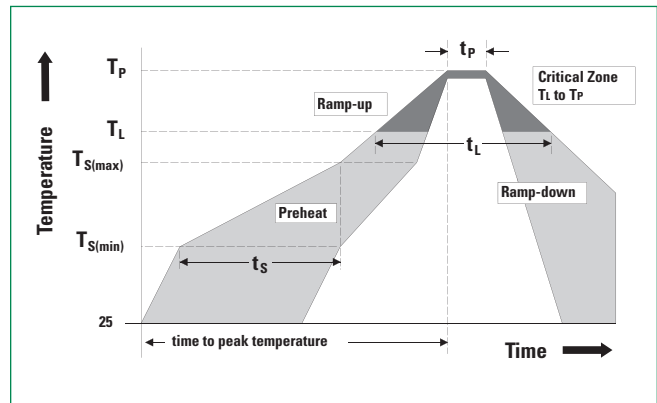


**IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage**



**Soldering Parameters**

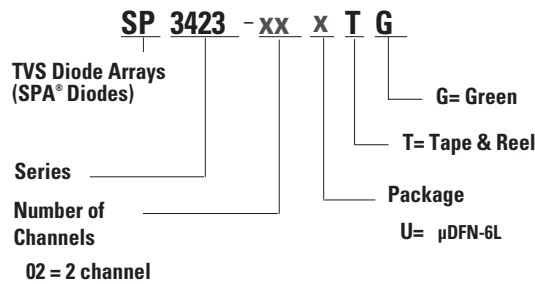
<b>Reflow Condition</b>		Pb – Free assembly
<b>Pre Heat</b>	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 180 secs
<b>Average ramp up rate (Liquidus) Temp (<math>T_L</math>) to peak</b>		3°C/second max
<b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>		3°C/second max
<b>Reflow</b>	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Temperature ( $t_t$ )	60 – 150 seconds
<b>Peak Temperature (<math>T_p</math>)</b>		260 <sup>+0/-5</sup> °C
<b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>		20 – 40 seconds
<b>Ramp-down Rate</b>		6°C/second max
<b>Time 25°C to peak Temperature (<math>T_p</math>)</b>		8 minutes Max.
<b>Do not exceed</b>		260°C



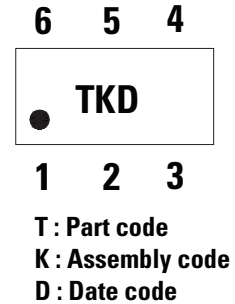
**Ordering Information**

Part Number	Package	Min. Order Qty.
SP3423-02UTG	μDFN-6L	3000

**Part Numbering System**



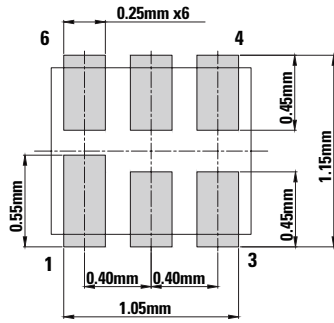
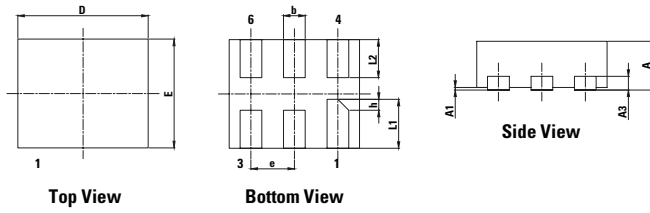
**Part Marking System**



**Product Characteristics**

<b>Lead Plating</b>	Pre-Plated Frame (μDFN)
<b>Lead Material</b>	Copper Alloy
<b>Substrate Material</b>	Silicon
<b>Body Material</b>	Molded Compound
<b>Flammability</b>	UL Recognized compound meeting flammability rating V-0

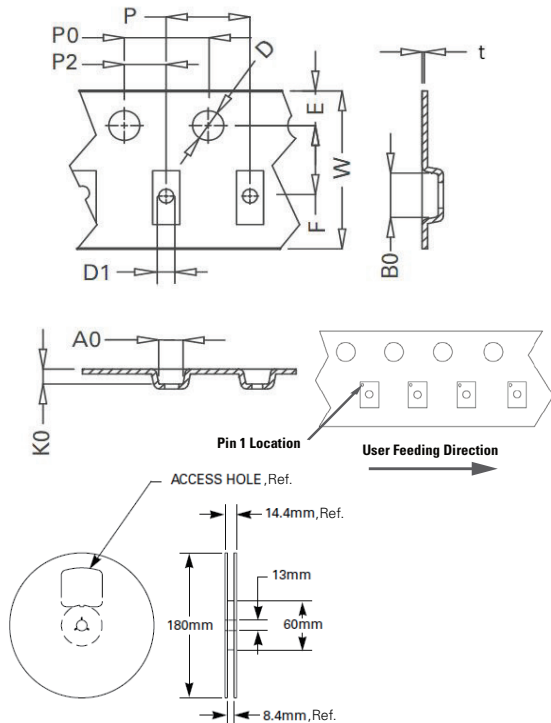
**Package Dimensions – μDFN-6L**



**Recommended Soldering Pad Layout**  
Drawing#: U02-A

μDFN6 (1.2x1.0x0.45mm)						
JEDEC MO-229						
Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	0.40	0.45	0.50	0.016	0.018	0.020
A1	0.00	0.02	0.05	0.000	0.001	0.002
A3	0.125 REF			0.005 REF		
b	0.15	0.20	0.25	0.006	0.008	0.010
D	1.10	1.20	1.30	0.043	0.047	0.051
E	0.90	1.00	1.10	0.035	0.039	0.043
e	0.40 REF			0.016 BSC		
L1	0.35	0.45	0.55	0.014	0.018	0.022
L2	0.25	0.35	0.45	0.010	0.014	0.018
h	0.10 REF			0.004 REF		

**Embossed Carrier Tape & Reel Specification – μDFN-6L**



**8mm TAPE AND REEL**

Symbol	Millimeters		Inches	
	Min	Max	Min	Max
E	1.65	1.85	0.064	0.073
F	3.45	3.55	0.135	0.139
P2	1.95	2.05	0.076	0.081
D	1.40	1.60	0.055	0.063
D1	0.45	0.55	0.017	0.021
P	3.90	4.10	0.154	0.161
10P0	40.0+/-0.20		1.574+/-0.008	
W	7.90	8.30	0.311	0.319
P0	3.90	4.10	0.154	0.161
A0	1.15	1.25	0.045	0.049
B0	1.75	1.85	0.069	0.073
K0	0.65	0.75	0.026	0.03
t	0.22 max		0.009 max	

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